TEXAS INSTRUMENTS

Data sheet acquired from Harris Semiconductor SCHS066

CD4099B Types

CMOS 8-Bit Addressable Latch

High-Voltage Types (20-Volt Rating)

■ CD4099B 8-bit addressable latch is a serial-input, parallel-output storage register that can perform a variety of functions.

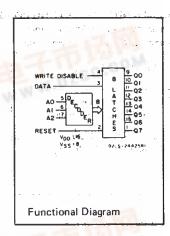
Data are inputted to a particular bit in the latch when that bit is addressed (by means of inputs A0, A1, A2) and when WRITE DISABLE is at a low level. When WRITE DISABLE is high, data entry is inhibited; however, all 8 outputs can be continuously read independent of WRITE DISABLE and address inputs.

A master RESET input is available, which resets all bits to a logic "0" level when RESET and WRITE DISABLE are at a high level. When RESET is at a high level, and WRITE DISABLE is at a low level, the latch acts as a 1-of-8 demultiplexer; the bit that is addressed has an active output which follows the data input, while all unaddressed bits are held to a logic "0" level.

The CD4099B types are supplied in 16-lead hermetic ceramic dual-in-line packages (D and F suffixes), 16-lead plastic dual-in-line packages (E suffix), and in chip form (H suffix)

Features:

- Serial data input Active parallel output
- Storage register capability Master clear
- Can function as demultiplexer
- Standardized, symmetrical output characteristics
- 100% tested for quiescent current at 20 V
- Maximum input current of 1 μA at 18 V (full package-temperature range), 100 nA at 18 V and 25°C
- Noise margin (full package-temperature range) = 1 V at V_{DD} = 5 V, 2 V at V_{DD} = 10 V, 2.5 V at V_{DD} = 15 V
- 5-V, 10-V, and 15-V parametric ratings
- Meets all requirements of JEDEC Tentative Standard No. 13B, "Standard Specifications for Description of 'B' Series CMOS Devices"

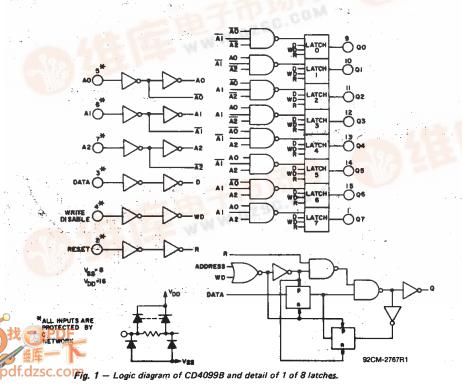


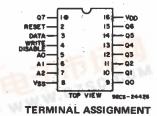
Applications:

- Multi-line decoders
- A/D converters

MAXIMUM RATINGS, Absolute-Maximum Values:	
DC SUPPLY-VOLTAGE RANGE, (VDD)	Stable Stable
Voltages referenced to VSS Terminal)	0.5V to +20V
INPUT VOLTAGE RANGE, ALL INPUTS	0.5V to V _{DD} +0.5V
DC INPUT CURRENT, ANY ONE INPUT	
POWER DISSIPATION PER PACKAGE (PD):	
For T _A = -55°C to +100°C	500mW
For T _A = +100°C to +125°C Derate Line	earity at 12mW/OC to 200mW
DEVICE DISSIPATION PER OUTPUT TRANSISTOR	THE PARTY OF
FOR TA = FULL PACKAGE-TEMPERATURE RANGE (All Package Types)	100mW
OPERATING-TEMPERATURE RANGE (TA)	55°C to +125°C
STORAGE TEMPERATURE RANGE (Tato)	65°C to +150°C
LEAD TEMPERATURE (DURING SOLDERING):	e se e

At distance $1/16 \pm 1/32$ inch $(1.59 \pm 0.79$ mm) from case for 10s max





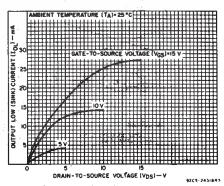


Fig. 2 — Typical output low (sink) current characteristics.

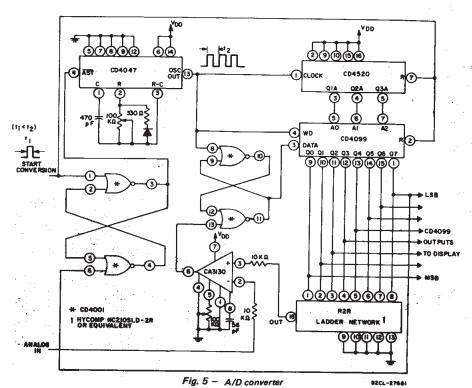
CD4099B Types

RECOMMENDED OPERATING CONDITIONS at $T_A = 25^\circ$ C (Unless otherwise specified) For maximum reliability, nominal operating conditions should be selected so that operation is always within the following ranges.

CHARACTERISTIC	SEE	v_{DD}	LIMITS		UNITS	
	FIG. 15*	(V)	MIN.	MAX.	UNITS	
Supply Voltage Range: (At T _A = Full Package Temperature Range)			3	.18	v ,	
Minimum Pulse Width, tW		5	200	-		
Data	(4)	10	100	-		
		15	80		٠.	
		5	400	_	ns	
Address	8	10	200	74 - 3 g 	113	
		15	125		-	
		5	150		•	
Reset	(5)	10	75	_		
		15	50	_		
Setup Time, t _S		5	100	-		
Data to WRITE DISABLE	(6)	10	50	. –		
		15	35	-	ns	
Hold Time, t _H		5	150	_		
Data to WRITE DISABLE		10	75	_	ns	
		15	50			

^{*} Circled numbers refer to times indicated on master timing diagram.

Note: In addition to the above characteristics, a WRITE DISABLE ON time (the time that WRITE DISABLE is at a high level) must be observed during an address change for the total time that the external address lines AO, A1, and A2 are settling to a stable level, to prevent a wrong cell from being addressed (see Fig. 3).



MODE SELECTION						
WD	R ADDRESSED UNADDRESSE LATCH					
0	0	Follows Data	Holds Previous State			
0	1	Follows Data Reset to "0"				
		(Active High 8-Channel Demulti-				
1	0	Holds Previous State				
1	1	Reset to "0"	Reset to "0"			

WD = WRITE DISABLE

R = RESET

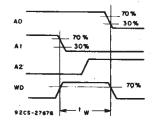


Fig. 3 - Definition of WRITE DISABLE ON time.

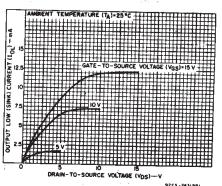


Fig. 4 — Minimum output low (sink) current characteristics.

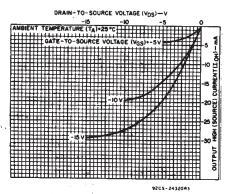
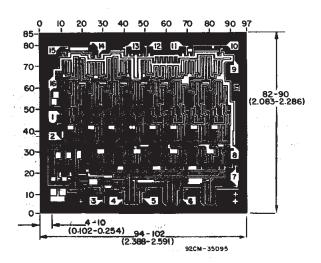


Fig. 6 — Typical output high (source) current characteristics,

CD4099B Types

STATIC ELECTRICAL CHARACTERISTICS

CHARACTER-	CONDITIONS			LIMITS AT INDICATED TEMPERATURES (°C)							
ISTIC	٧q	VIN	VDD					+25			UNITS
	(V)	(V)	(V)	-55	-4 0	+85	+125	Min.	Тур.	Max.	
Quiescent Device Current,		0,5	5	5	5	150	150		0.04	5	μА
		0,10	10	10	10	300	300	-	0.04	10	
IDD Max.	_	0,15	15	20	20	600	600	_	0.04	20	
	-	0,20	20	100	100	3000	3000	-	0.08	100	
Output Low	0.4	0,5	5	0.64	0,61	0.42	0.36	0.51	1	_	
(Sink) Current	0.5	0,10	10	1.6	1.5	1.1	0.9	1.3	2.6	- .	
IOL Min.	1.5	0,15	15	4.2	4	2.8	2.4	3 4	6.8	_ "	
Output High	4.6	0,5	5	-0.64	-0.61	-0.42	0.36	-0.51	-1	-	mA
(Source)	2.5	0,5	5	-2	-1.8	-1.3	-1.15	-1.6	-3.2	_	
Current,	9.5	0,10	10	-1.6	-1.5	-1.1	-0.9	-1.3	-2.6		
IOH Min.	13.5	0,15	15	-4.2	-4	-2.8	-2.4	-3.4	-6.8	- .	
Output Voltage:	<u>-</u>	0,5	5	0.05			-	0	0.05		
Low-Level, VOI Max.	-	0,10	10	0.05				_	0	0.05	v
AOF Max.	-	0,15	15	0.05			-	0	0.05		
Output Voltage:	-	0,5	5	4.95			4.95	5	-	•	
High-Level,	-	0,10	10	9.95				9.95	10 .	-	
VOH Min.	_	0,15	15	14.95				14.95	15		
Input Low Voltage, VIL Max.	0.5, 4.5		5	1.5				_		1.5	
	1, 9	_	10	3				_	_	3	
	1.5,13.5	_	15	4				_	_	4	v
Input High Voltage, VIH Min.	0.5, 4.5	-	5	3.5			3.5	_	-	\ \	
	1, 9	_	10	7				7			1
	1.5,13.5	-	15	11 1			11				
Input Current IIN Max.	_	0,18	18	±0.1	±0.1	±1	±1	-	±10-5	±0.1	μΑ



CD4099BH DIMENSIONS AND PAD LAYOUT

Dimensions in parentheses are in millimeters and are derived from the basic inch dimensions as indicated. Grid graduations are in mils (10⁻³ inch).

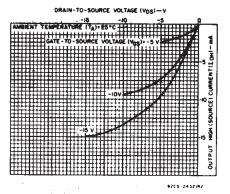


Fig.7 - Minimum output high (source) current characteristics.

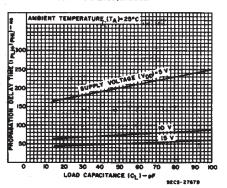


Fig. 8 - Typical propagation delay time (data to Qn) vs. load capacitance.

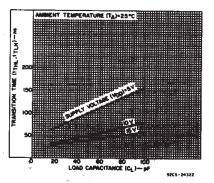


Fig. 9 — Typical transition time vs. load capacitance.

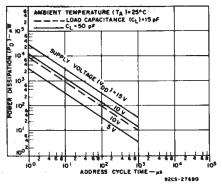


Fig. 10 – Typical dynamic power dissipation vs. address cycle time.

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DYNAMIC ELECTRICAL CHARACTERISTICS at T_A = 25° C, C_L = 50 pF, Input t_p , t_f = 20 ns, R_L = 200 K Ω

CHARACTERISTIC	CONDI SEE FIG.15*	V _{DD}	ALL PACI	UNITS	
Propagation Delay: tpLH,		5	200	MAX. 400	
tPHL	1	10	75	150	
Data to Output,		15	50	100	
WRITE DISABLE	 	5	200	400	
to Output, tpLH,	2	10	80	160	ns
t _{PHL}		15	60	120	
		5	175	350	
Reset to Output,	3	10	80	160	
t _{PHL}		15	65	130	-
Address to Output,		5	225	450	
tPLHV	9	10	100	200	:
tPHL to the tent t		15	75	150	
Transition Time, t _{THL} ,		5	100	200	···· .
(Any Output) t _{TLH}		10	50	100	ns
		15	40	80	
Minimum Pulse	_	5	100	200	
Width, t _W	4	10	50	100	ns
Data		15	40	. 80	
		5	200	400	
Address	8 [10	100	200	ns
	ļ	15	65	125	
		5	75	150	
Reset	5	10	40	75	ns
		15	25	50	
Minimum Setup		5	50	100	
Time, t _S	6	10	25	50	ns
Data to WRITE DISABLE		15	20	35	
Minimum Hold		5	75	150	
Time, t _H	0 [10	40	75	ns
Data to WRITE DISABLE		15	25	50	
Input Capacitance, CIN	Any Inp	ut	5	7.5	pF

^{*}Circled numbers refer to times indicated on master timing diagram.

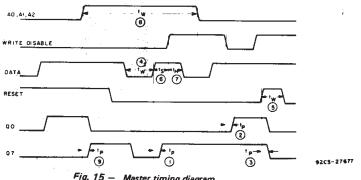


Fig. 15 — Master timing diagram.

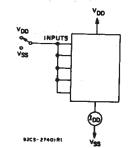


Fig. 11 - Quiescent device current test circuit.

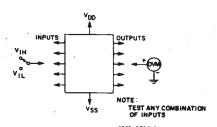


Fig. 12 - Input voltage test circuit.

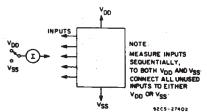


Fig. 13 - Input current test circuit.

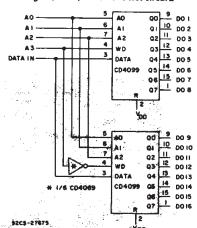


Fig. 14 - 1 of 16 decoder/demuttiplexer.

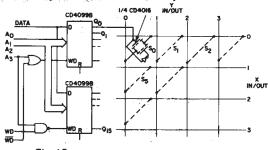


Fig. 16 - Multiple selection decoding - 4 x 4 crosspoint switch.

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